

Standard Recovery Diodes, (Stud Version), 40 A



DO-203AB (DO-5)

PRODUCT SUMMARY				
I _{F(AV)}	40 A			
Package	DO-203AB (DO-5)			
Circuit configuration	Single diode			

FEATURES

- · High surge current capability
- Stud cathode and stud anode version



- Leaded version available
- Types up to 1600 V V_{RRM}
- Designed and qualified for multiple level
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- · Battery charges
- Converters
- Power supplies
- Machine tool controls
- Welding

MAJOR RATINGS AND CHARACTERISTICS					
	TEST COMPLETIONS	40H	IF(R)	UNITS	
PARAMETER	TEST CONDITIONS —	10 TO 120	140/160		
1		40	40	Α	
I _{F(AV)}	T _C	140	110	°C	
I _{F(RMS)}		62	62	Α	
1	50 Hz	570	570	A	
IFSM	60 Hz	595	595		
2t	50 Hz	1600	1600	A ² s	
1-1	60 Hz	1450	1450		
V _{RRM}	Range	100 to 1200	1400 to 1600	V	
TJ		-65 to 190	-65 to 160	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$\begin{aligned} & I_{RRM} \text{ MAXIMUM} \\ \text{AT T}_{J} &= T_{J} \text{ MAXIMUM} \\ & \text{mA} \end{aligned}$	
	10	100	200		
	20	200	300		
	40	400	500		
	60	600	700	9	
	80	800	900		
	100	1000	1100		
	120	1200	1300		
	140	1400	1500	4.5	
	160	1600	1700	4.5	



FORWARD CONDUCTION							
DADAMETED	CVMPOL	TEST COMPLETIONS			40HF(R)		
PARAMETER	SYMBOL	TEST CONDITIONS		10 TO 120	140/160	UNITS	
Maximum average forward current at case temperature	I _{F(AV)}	180° conduction, half sine wave		40 140	40 110	A °C	
Maximum RMS forward current	I _{F(RMS)}				62	2	Α
		t = 10 ms	No voltage		57	0	
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied		595		_
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		480		A
		t = 8.3 ms	reapplied	Sinusoidal half wave,	500		
	l ² t	t = 10 ms	$ \begin{array}{c} \text{No voltage} \\ \text{reapplied} \end{array} \text{ initial } T_J = T_J \text{ maximum} $	1600			
Maximum I ² t for fusing		t = 8.3 ms			1450		A ² s
Maximum From Idsing		t = 10 ms	100 % V _{RRM}		1150		
		t = 8.3 ms	reapplied		1050		
Maximum $I^2\sqrt{t}$ for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied		16 (000	A²√s	
Value of threshold voltage (up to 1200 V)	V _{F(TO)}	$T_J = T_J$ maximum		0.6	35	V	
Value of threshold voltage (for 1400 V/1600 V)	V _{F(TO)}			0.76		76	v
Value of forward slope resistance (up to 1200 V)	r _f	T _J = T _J maximum		4.29		29	mΩ
Value of forward slope resistance (for 1400 V/1600 V)	r _f			3.8		8	11152
Maximum forward voltage drop	V_{FM}	$I_{pk} = 125 \text{ A}, T_J = 25 \text{ °C}, t_p = 400 \mu \text{s rectangular wave}$ 1.30		1.30	1.50	V	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TECT COMPLETIONS	40H	40HF(R)	
PARAMETER		TEST CONDITIONS	10 to 120	140 to 160	UNITS
Maximum junction operating and storage temperature range	T _J , T _{Stg}		-65 to 190	-65 to 160	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation 0.95		95	K/W
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25		
		Not lubricated thread, tighting on nut (1)	3.4	(30)	
Maximum allowable mounting		Lubricated thread, tighting on nut (1)	2.3	2.3 (20)	
torque (+0 %, -10 %)		Not lubricated thread, tighting on hexagon (2)	4.2 (37)		(lbf · in)
		Lubricated thread, tighting on hexagon (2)	3.2	(28)	
Approximate weight			1	7	g
Approximate weight			0	.6	OZ.
Case style		See dimensions - link at the end of datasheet DO-203AB (DO		-203AB (DO-	5)

Notes

⁽²⁾ Recommended for holed threaded heatsinks

△R _{th} JC CONDUCTION					
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.14	0.10			
120°	0.16	0.17			
90°	0.21	0.22	$T_J = T_J$ maximum	K/W	
60°	0.30	0.31			
30°	0.50	0.50	1		

Note

The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

⁽¹⁾ Recommended for pass-through holes

www.vishay.com

Vishay Semiconductors

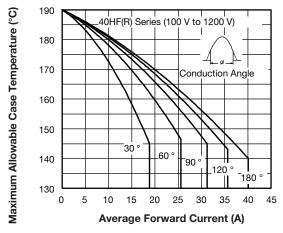


Fig. 1 - Current Ratings Characteristics

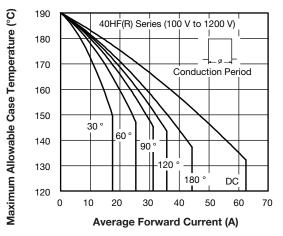


Fig. 2 - Current Ratings Characteristics

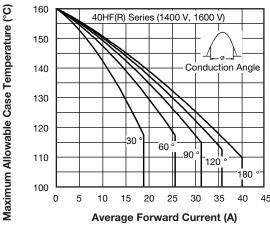


Fig. 3 - Current Ratings Characteristics

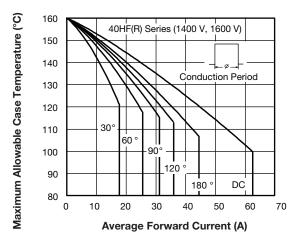


Fig. 4 - Current Ratings Characteristics

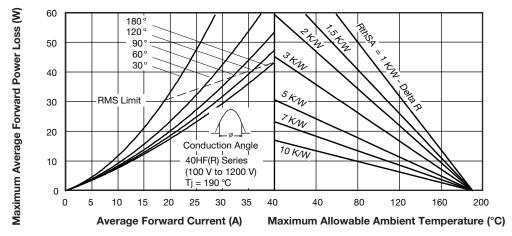


Fig. 5 - Forward Power Loss Characteristics

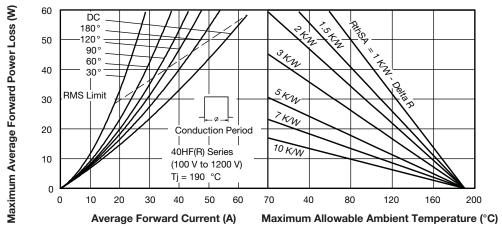


Fig. 6 - Forward Power Loss Characteristics

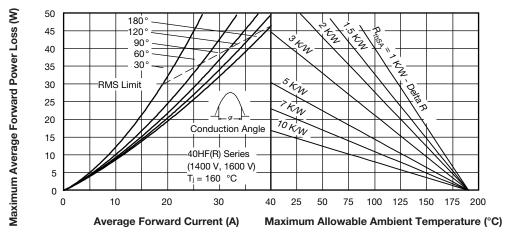


Fig. 7 - Forward Power Loss Characteristics

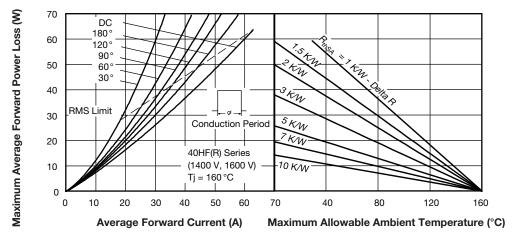


Fig. 8 - Forward Power Loss Characteristics

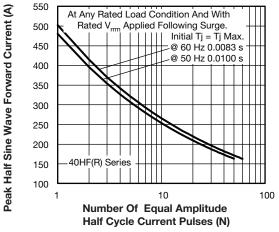


Fig. 9 - Maximum Non-Repetitive Surge Current

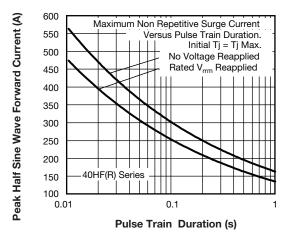


Fig. 10 - Maximum Non-Repetitive Surge Current

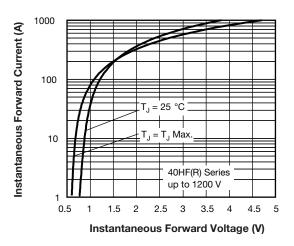


Fig. 11 - Forward Voltage Drop Characteristics (Up To 1200 V)

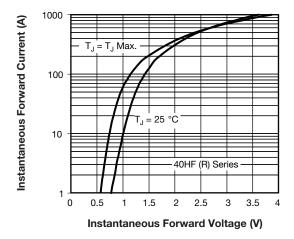


Fig. 12 - Forward Voltage Drop Characteristics (For 1400 V/1600 V)

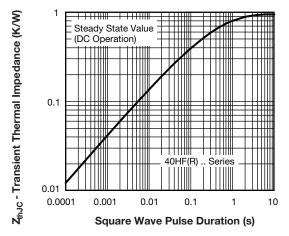
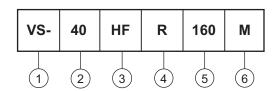


Fig. 13 - Thermal Impedance ZthJC Characteristics



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

• 40 = Standard device

• 41 = Not isolated lead

• 42 = Isolated lead with silicone sleeve

(red = Reverse polarity)

(blue = Normal polarity)

3 - HF = Standard diode

None = Stud normal polarity (cathode to stud)

• R = Stud reverse polarity (anode to stud)

5 - Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

- None = Stud base DO-203AB (DO-5) 1/4" 28UNF-2A

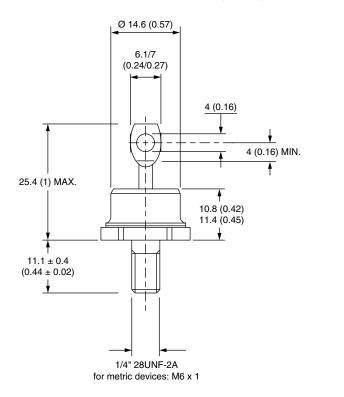
• M = Stud base DO-203AB (DO-5) M6 x 1

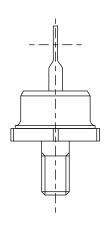
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95344		

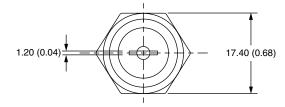


DO-203AB (DO-5) for 40HF(R) and 41HF(R) Series

DIMENSIONS FOR 40HF(R) SERIES in millimeters (inches)







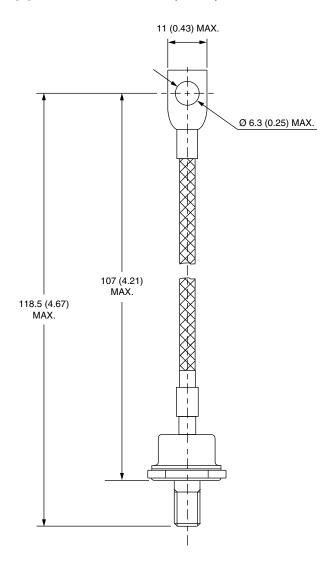
Outline Dimensions

Vishay Semiconductors

DO-203AB (DO-5) for 40HF(R) and 41HF(R) Series



DIMENSIONS FOR 41HF(R) SERIES in millimeters (inches)





Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.